

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[Sanken](#)
[STD01N](#)

For any questions, you can email us directly:

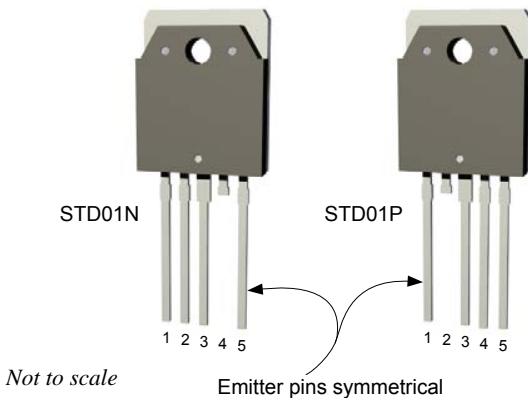
sales@integrated-circuit.com

Darlington Transistors for Audio Amplifiers

Features and Benefits

- Built-in temperature compensation diodes
- High power (100 W) handling in a small package (TO-3P), for minimized heat sink requirements
- Built-in drivers and temperature compensation diodes, reducing external component count and simplifying circuit design
- NPN and PNP versions
- Emitter terminals placed symmetrically, pin 5 on NPN and pin 1 on PNP models, allowing adjacent placement on PCB to minimize trace length and output skew when used in pairs
- Approved by major manufacturers

Package: 5 pin TO-3P (MT-100)



Description

The STD01N and STD01P are enhanced Darlington transistors with built-in drivers and temperature compensation diode. Manufactured using the unique Sanken thin-wafer production technology, these devices achieve higher power levels through decreased thermal resistance, and can withstand higher voltages than similar devices on the market.

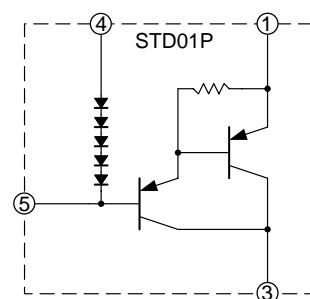
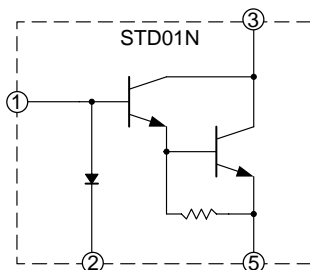
The temperature compensation diode is integrated on the same chip as the power transistors. By this design, the STD01N and STD01P eliminate delays that would otherwise be induced between thermal sensing at the heat source, and the operation of the compensation circuitry. Thus, these transistors are ideal for applications where enhanced thermal stability is required.

This device is provided in a 5-pin TO-3P plastic package with pin 4 removed. Contact SankenTM for application support and additional information on device performance.

Applications include:

- General amplifier applications
- Professional audio amplifiers
- Car audio amplifiers

Equivalent Circuits



STD01N and STD01P

Darlington Transistors for Audio Amplifiers

SELECTION GUIDE

Part Number	Type	h _{FE} Rating	Packing
STD01N*	NPN	Range O: 5000 to 12000	Bulk, 100 pieces
		Range Y: 8000 to 20000	
STD01P*	PNP	Range O: 5000 to 12000	
		Range Y: 8000 to 20000	

*Specify h_{FE} range when ordering. If no h_{FE} range is specified, order will be fulfilled with either or both range O and range Y, depending upon availability.

ABSOLUTE MAXIMUM RATINGS at T_A = 25°C

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage ¹	V _{CBO}	150	V
Collector-Emitter Voltage ¹	V _{CEO}	150	V
Emitter-Base Voltage ¹	V _{EBO}	5	V
Collector Current ¹	I _C	10	A
Base Current ¹	I _B	1	A
Collector Power Dissipation ²	P _C	100	W
Diode Forward Current	I _F	10	mA
Junction Temperature	T _J	150	°C
Storage Temperature	T _{stg}	-55 to 150	°C

¹For PNP type (STD01P), voltage and current values are negative.

²T_C = 25°C.

ELECTRICAL CHARACTERISTICS at T_A = 25°C

Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Unit	
Collector-Cutoff Current ¹	I _{CBO}	V _{CB} = 150 V	-	-	100	μA	
Emitter Cutoff Current ¹	I _{EBO}	V _{EB} = 5 V	-	-	100	μA	
Collector-Emitter Voltage ¹	V _{CEO}	I _C = 30 mA	150	-	-	V	
DC Current Transfer Ratio ^{2,3}	h _{FE}	V _{CE} = 4 V, I _C = 6 A	5000	-	20000	-	
Collector-Emitter Saturation Voltage ¹	V _{CE(sat)}	I _C = 6 A, I _B = 6 mA	-	-	-2.0	V	
Base-Emitter Saturation Voltage ¹	V _{BE(sat)}	I _C = 6 A, I _B = 6 mA	-	-	-2.5	V	
Base-Emitter Voltage	V _{BE}	STD01N	V _{CE} = 20 V, I _C = 40 mA	-	1220	-	mV
		STD01P	V _{CE} = -20 V, I _C = -40 mA	-	1230	-	mV
Diode Forward Voltage	V _F	STD01N	I _F = 2.5 mA	-	705	-	mV
		STD01P	I _F = 2.5 mA	-	1580	-	mV

¹For PNP type (STD01P), voltage and current values are negative.

²h_{FE} rating: 5000 to 12000(O brand on package), 8000 to 20000 (Y).

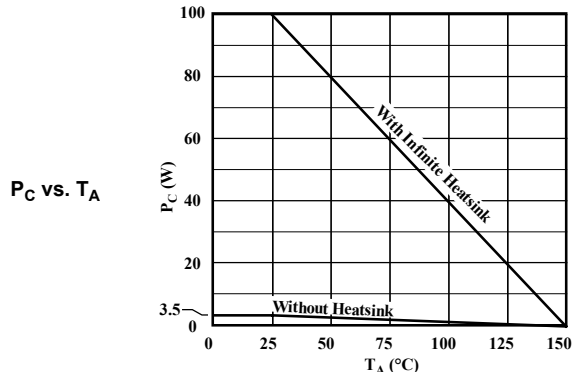
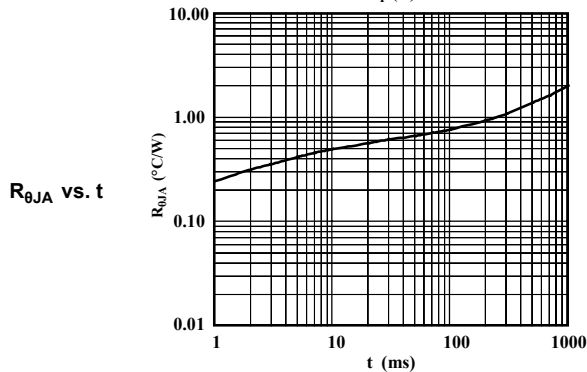
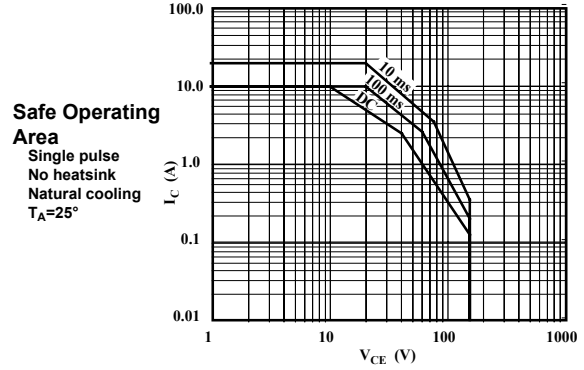
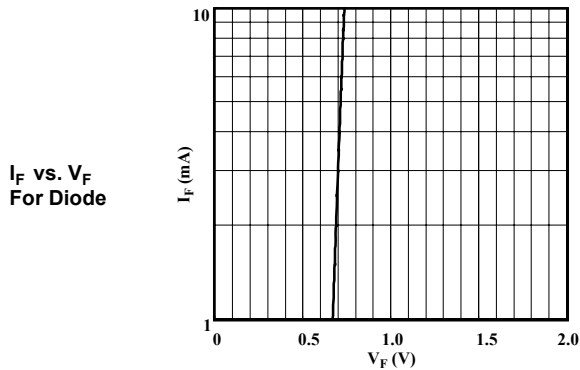
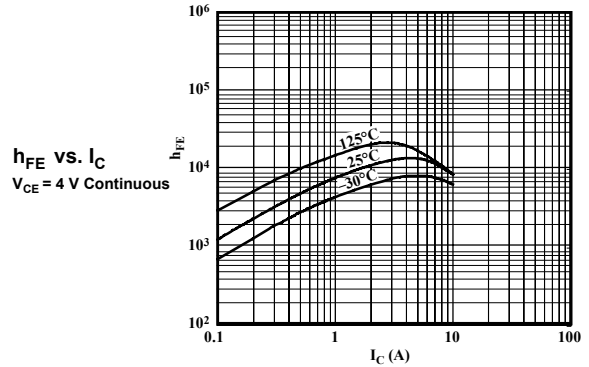
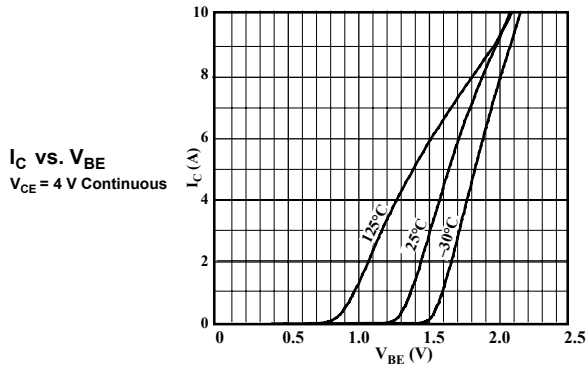
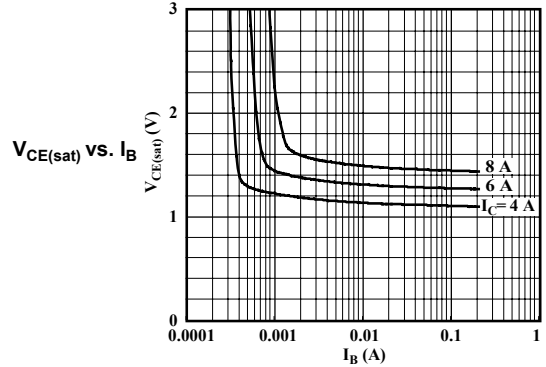
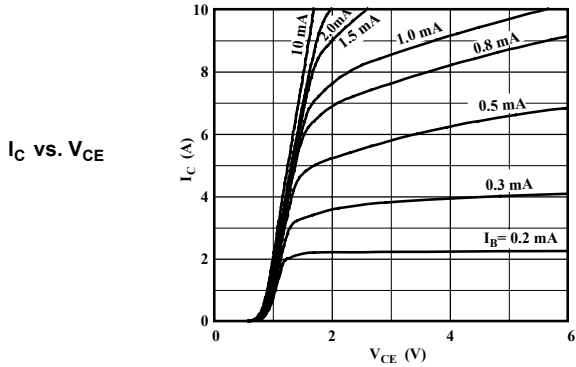
³When the transistor is used in pairs, the following conditions must be satisfied: Total V_F ≤ Total V_{BE} of the transistors (the above measurement conditions shall be applied), and ΔV = 0 to 500 mV.

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature of +25°C, unless otherwise stated.

**STD01N and
STD01P**

Darlington Transistors for Audio Amplifiers

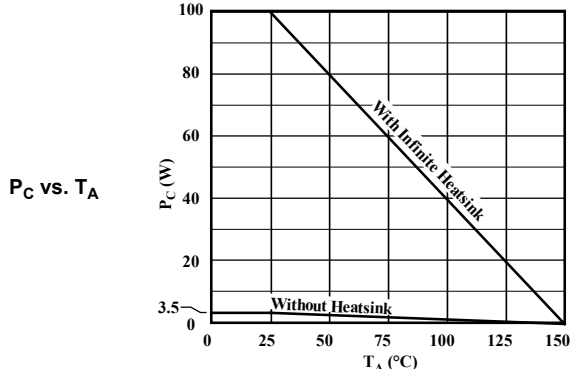
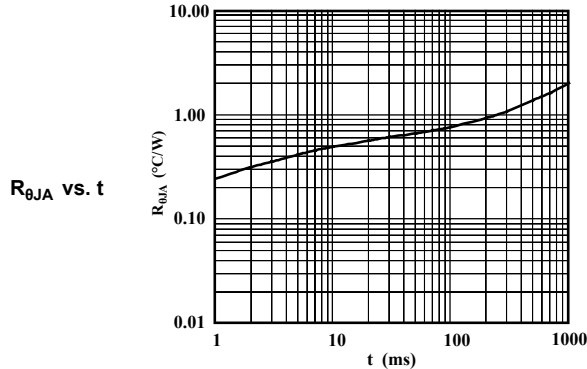
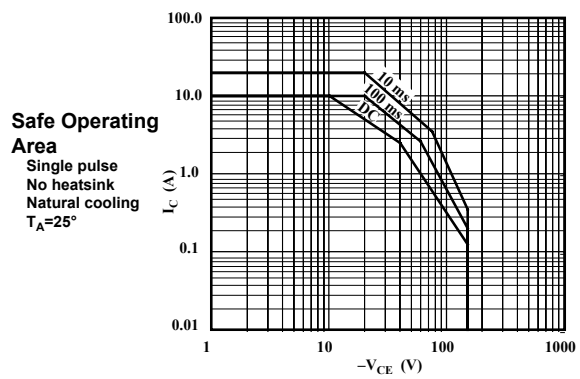
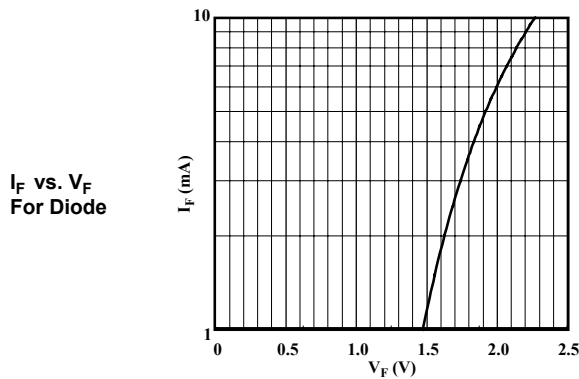
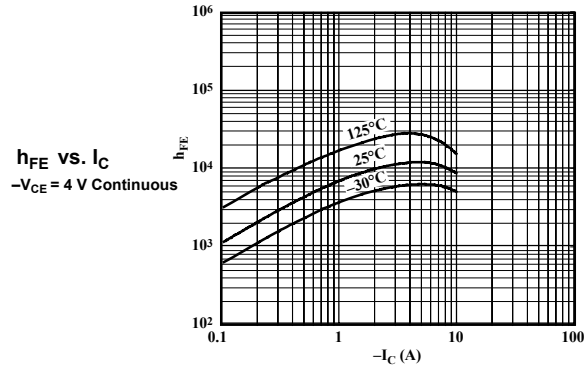
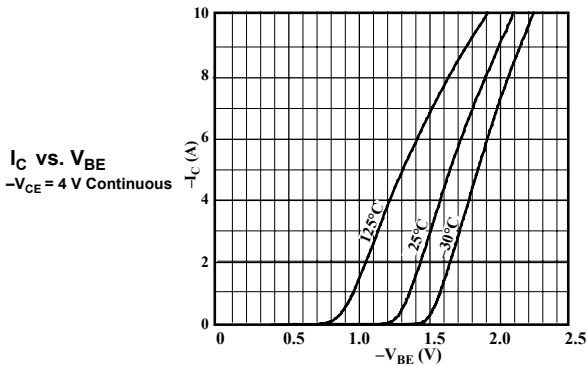
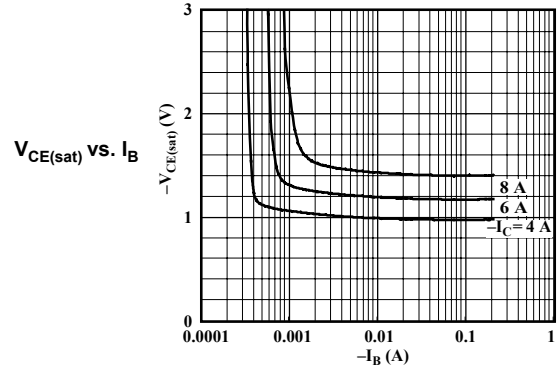
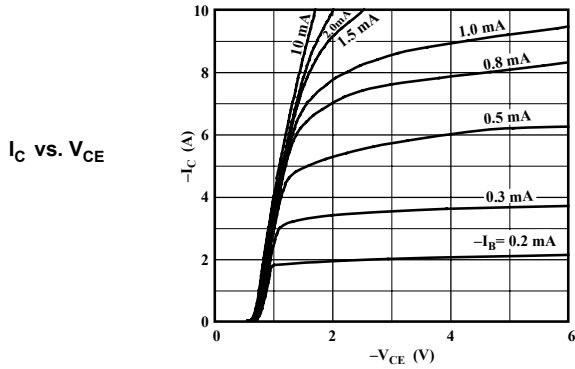
STD01N Performance Characteristics at $T_A = 25^\circ\text{C}$



**STD01N and
STD01P**

Darlington Transistors for Audio Amplifiers

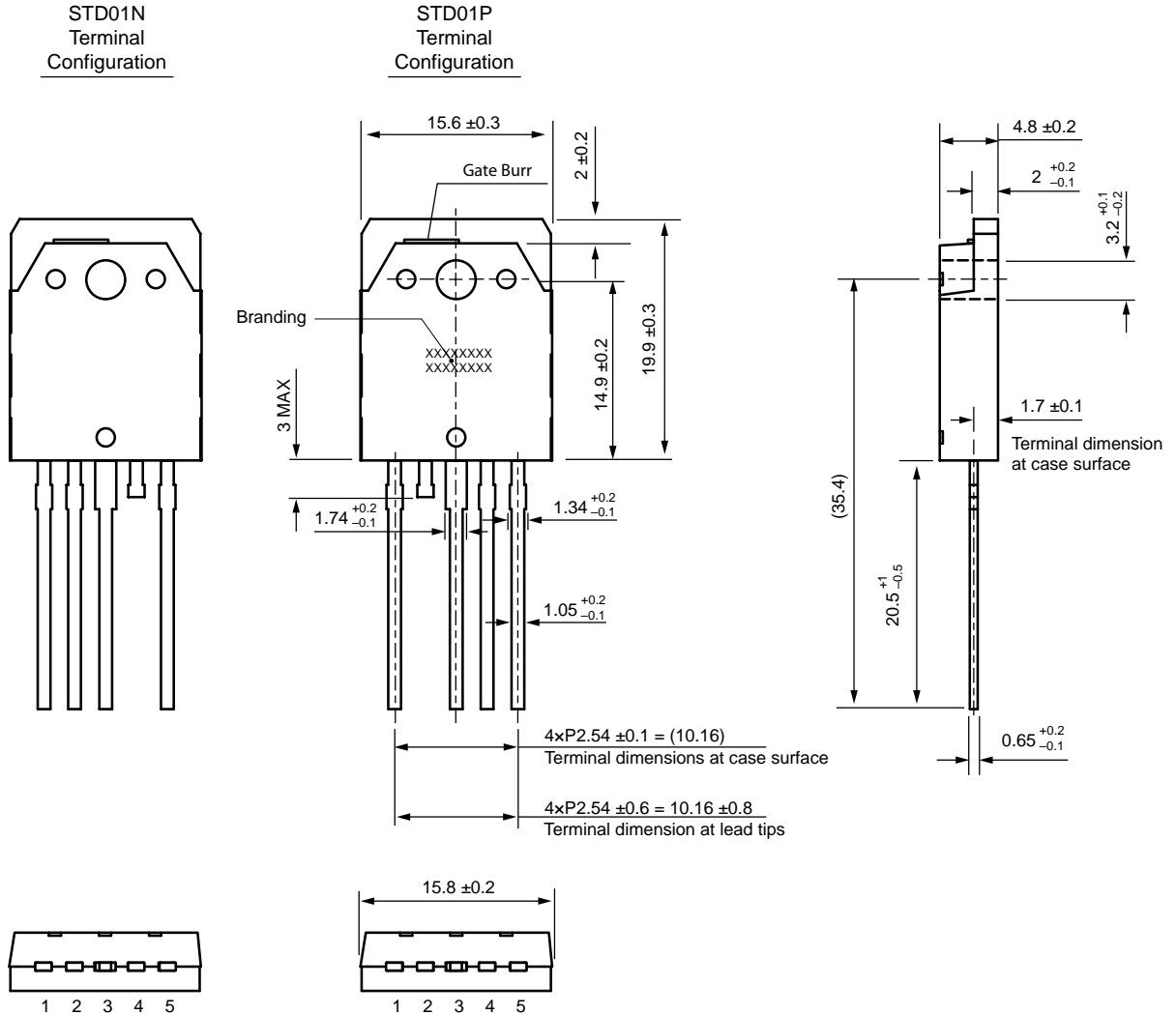
STD01P Performance Characteristics at $T_A = 25^\circ\text{C}$



**STD01N and
STD01P**

Darlington Transistors for Audio Amplifiers

PACKAGE OUTLINE DRAWING, TO-3P



Gate burr: 0.3 mm (max.), mold flash may appear at opposite side
 Terminal core material: Cu
 Terminal treatment: Ni plating and solder dip
 Heat sink material: Cu
 Heat sink treatment: Ni plating
 Leadform: 2804
 Weight (approximate): 6.0 g

Dimensions in millimeters

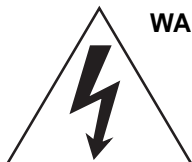
Branding codes (exact appearance at manufacturer discretion):
 1st line, type: STD01X
 Where: X is the transistor type (N or P)
 2nd line, lot: YMDD H
 Where: Y is the last digit of the year of manufacture
 M is the month (1 to 9, O, N, D)
 DD is the 2-digit date
 H is the h_{FE} rating (O or Y; for values see footnote, Electrical Characteristics table)



Leadframe plating Pb-free. Device composition includes high-temperature solder (Pb >85%), which is exempted from the RoHS directive.

STD01N and STD01P

Darlington Transistors for Audio Amplifiers



WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust in leads and solderability of products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce stress.
- Volatile-type silicone greases may produce cracks after long periods of time, resulting in reduced heat radiation effect. Silicone grease with low consistency (hard grease) may cause cracks in the mold resin when screwing the product to a heatsink.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Toshiba Silicone Co., Ltd.
SC102	Dow Corning Toray Silicone Co., Ltd.

Heatsink Mounting Method

- Torque When Tightening Mounting Screws. Thermal resistance increases when tightening torque is low, and radiation effects are decreased. When the torque is too high, the screw can strip, the heatsink can be deformed, and distortion can arise in the product frame. To avoid these problems, observe the recommended tightening torques for this product package type, TO-3P (MT-100): 0.686 to 0.882 N•m (7 to 9 kgf•cm).
- Diameter of Heatsink Hole: < 4 mm. The deflection of the press mold when making the hole may cause the case material to crack at the joint with the heatsink. Please pay special attention for this effect.

Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:
 260±5°C 10 s
 350±5°C 3 s
- Soldering iron should be at a distance of at least 1.5 mm from the body of the products

Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.

STD01N and STD01P

Darlington Transistors for Audio Amplifiers

The products described herein are manufactured in Japan by Sanken Electric Co., Ltd.

Sanken reserves the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Therefore, the user is cautioned to verify that the information in this publication is current before placing any order.

When using the products described herein, the applicability and suitability of such products for the intended purpose shall be reviewed at the users responsibility.

Although Sanken undertakes to enhance the quality and reliability of its products, the occurrence of failure and defect of semiconductor products at a certain rate is inevitable.

Users of Sanken products are requested to take, at their own risk, preventative measures including safety design of the equipment or systems against any possible injury, death, fires or damages to society due to device failure or malfunction.

Sanken products listed in this publication are designed and intended for use as components in general-purpose electronic equipment or apparatus (home appliances, office equipment, telecommunication equipment, measuring equipment, etc.). Their use in any application requiring radiation hardness assurance (e.g., aerospace equipment) is not supported.

When considering the use of Sanken products in applications where higher reliability is required (transportation equipment and its control systems or equipment, fire- or burglar-alarm systems, various safety devices, etc.), contact a company sales representative to discuss and obtain written confirmation of your specifications.

The use of Sanken products without the written consent of Sanken in applications where extremely high reliability is required (aerospace equipment, nuclear power-control stations, life-support systems, etc.) is strictly prohibited.

The information included herein is believed to be accurate and reliable. Application and operation examples described in this publication are given for reference only and Sanken assumes no responsibility for any infringement of industrial property rights, intellectual property rights, or any other rights of Sanken or any third party that may result from its use.

Darlington Transistors for Audio Amplifiers

STD01N and STD01P

August, 2007

<Worldwide Contacts>

Asia Pacific

China

Sanken Electric Hong Kong Co., Ltd.

Suite 1026 Ocean Centre, Canton Road, Tsimshatsui, Kowloon, Hong Kong
Tel: 852-2735-5262
Fax: 852-2735-5494

Sanken Electric (Shanghai) Co., Ltd.

Room3202, Maxdo Centre, Xingyi Road 8, Changning district, Shanghai, China
Tel: 86-21-5208-1177
Fax: 86-21-5208-1757

India

Saket Devices Pvt. Ltd.

Office No.13, First Floor, Bandal - Dhankude Plaza, Near PMT Depot, Paud Road, Kothrud, Pune - 411 038, India
Tel: 91-20-5621-2340
91-20-2528-5449
Fax: 91-20-2528-5459

Japan

Sanken Electric Co., Ltd. Overseas Sales Headquarters

Metropolitan Plaza Bldg. 1-11-1 Nishi-Ikebukuro, Toshima-ku, Tokyo 171-0021, Japan
Tel: 81-3-3986-6164
Fax: 81-3-3986-8637

Korea

Sanken Electric Korea Co., Ltd.

Mirae Asset Life Bldg. 6F, 168 Kongduk-dong, Mapo-ku, Seoul, 121-705, Korea
Tel: 82-2-714-3700
Fax: 82-2-3272-2145

Singapore

Sanken Electric Singapore Pte. Ltd.

150 Beach Road, #14-03 The Gateway West, Singapore 189720
Tel: 65-6291-4755
Fax: 65-6297-1744

Taiwan

Taiwan Sanken Electric Co., Ltd.

Room 1801, 18th Floor, 88 Jung Shiau East Road, Sec. 2, Taipei 100, Taiwan R.O.C.
Tel: 886-2-2356-8161
Fax: 886-2-2356-8261

Darlington Transistors for Audio Amplifiers

STD01N and STD01P

August, 2007

Europe

United Kingdom

Sanken Power Systems (UK) Limited

Pencoed Technology Park Pencoed, Bridgend CF35 5HY. UK

Tel: 44-1656-869-100

Fax: 44-1656-869-162

North America

United States

Allegro MicroSystems, Inc.

115 Northeast Cutoff, Worcester, Massachusetts 01606, U.S.A.

Tel: 1-508-853-5000

Fax: 1-508-853-3353

Allegro MicroSystems, Inc. (Southern California)

14 Hughes Street, Suite B105, Irvine, CA 92618

Tel: 1-949-460-2003

Fax: 1-949-460-7837